



74AHC594

8-BIT SHIFT REGISTER WITH 8-BIT OUTPUT REGISTER

Description

The 74AHC594 is an advanced high speed CMOS device.

An eight bit shift register accepts data from the serial input (DS) on each positive transition of the shift register clock (SHCP). When asserted low the shift register reset function (SHR) sets all shift register values to zero and is independent of all clocks. Also when asserted low the storage register reset function (STR) sets all shift register values to zero and is independent of all clocks.

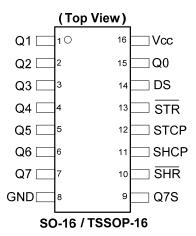
Data from the input serial shift register is placed in the output register with a rising pulse on the storages resister clock (STCP). The storage resister includes output Q7S which is used for cascading information between devices. As the information moves into the storage register, it is asserted on the push-pull outputs Q0-Q7.

All registers capture data on rising edge and change output on the falling edge. If both clocks are connected together, the input shift register is always one clock cycle ahead of the output register.

Features

- Wide Supply Voltage Range from 2.0V to 5.5V
- Sinks or sources 8mA at V_{CC} = 4.5V
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs
- Inputs accept up to 5.5V
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115-A)
 - Exceeds 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

- General Purpose Logic
- Serial to Parallel Data conversion
- Capture and hold data for extended periods of time.
- Allow simple serial bit streams from a microcontroller to control as many peripheral lines as needed
- Wide array of products such as:
 - Computer Peripherals
 - Appliances
 - Industrial Control

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

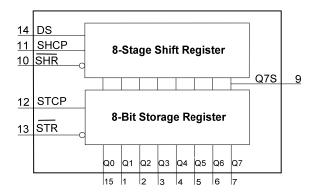
Click here for ordering information, located at the end of datasheet



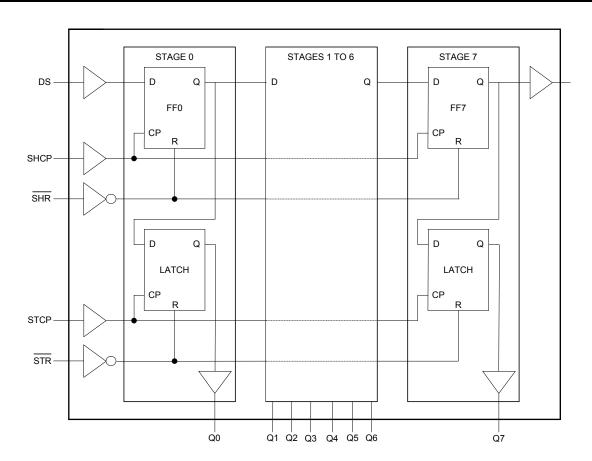
Pin Descriptions

Pin Number	Pin Name	Functions
1	Q1	Parallel Data Output 1
2	Q2	Parallel Data Output 2
3	Q3	Parallel Data Output 3
4	Q4	Parallel Data Output 4
5	Q5	Parallel Data Output 5
6	Q6	Parallel Data Output 6
7	Q7	Parallel Data Output 7
8	GND	Ground
9	Q7S	Serial Data Output
10	SHR	Shift Register Reset active low
11	SHCP	Shift Register Clock Input
12	STCP	Storage Register Clock Input
13	STR	Storage Register Reset active low
14	DS	Serial Data input
15	Q0	Parallel Data Output 0
16	Vcc	Supply Voltage

Functional Diagram



Logic Diagram

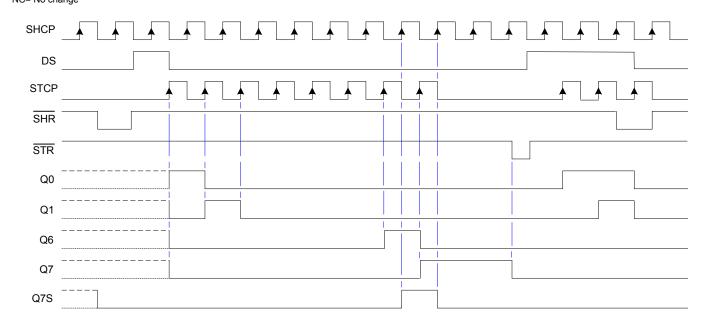




Functional Description and Timing Diagram

	Control			Input	Output		Forestina
SHR	STR	SHCP	STCP	DS	Q7S	Qn	Function
L	Х	Х	Х	Х	L	NC	Clear Shift Register
Х	L	Х	Х	Х	NC	L	Clear Storage Register
Н	Х	↑	L	H or L	Q6S	NC	Loads DS into shift register stage 0. All Q _S shifted
Н	Н	Х	1	Х	NC	Qs Contents of shift register moved to starge register all Q _S -> Q _N	
Н	Н	1	↑	H or L	Q6S	QnS	Shift Register one pulse count ahead of storage register.

H=HIGH voltage state L=LOW voltage state ↑=LOW to HIGH transition X= don't care – high or low (not floating) NC= No change



Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
Vcc	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range	-0.5 to +7.0	V
Vo	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V _I < -0.5V	-20	mA
lok	Output Clamp Current Vo<-0.5V	-20	mA
lok	Output Clamp Current V _O > V _{CC} +0.5V	20	mA
Io	Continuous output current	±25	mA
I _{CC}	Continuous current through Vcc	75	mA
I _{GND}	Continuous current through GND	-75	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
P _{TOT}	Total Power Dissipation	500	mW

Notes: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 5) (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
Vcc	Supply Voltage	_	2.0	5.5	V
VI	Input Voltage	_	0	5.5	V
Vo	Output Voltage	_	0	V _{CC}	V
A+/A\/	Input transition Disc or Fall Date	V _{CC} = 3.0V to 3.6V	-	100	20/1
Δt/ΔV	Input transition Rise or Fall Rate	V _{CC} = 4.5V to 5.5V	-	20	ns/V
T _A	Operating Free-Air Temperature	_	-40	+125	°C

Note:

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V	ΤA	= +25°	С	T _A = -40°C	to +85°C	$T_A = -40^{\circ}$	C to +125°C	Unit
Syllibol	Parameter	rest Conditions	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Oilit
		-	2.0V	1.5	-	_	1.5	_	1.5	-	
V_{IH}	High-Level Input Voltage	_	3.0V	2.1	_	_	2.1	-	2.1	-	V
	input voltage	-	5.5V	3.85	-	_	3.85	-	3.85	-	
		-	2.0V	_	-	0.5	-	0.5	-	0.5	
V_{IL}	Low-Level Input Voltage	-	3.0V	_	-	0.9	-	0.9	-	0.9	V
	input voltage	-	5.5V	_	-	1.65	-	1.65	-	1.65	
		$I_{OH} = -50 \mu A$	2.0V	1.9	2.0	_	1.9	-	1.9	-	
		I _{OH} = -50μA	3.0V	2.9	3.0	_	2.9	_	2.9	-	
VoH	V _{OH} High-Level Output Voltage	I _{OH} = -50μA	4.5V	4.4	4.5	_	4.4	-	4.4	-	V
	Output Voltage	I _{OH} = -4mA	3.0V	2.58	-	_	2.48	_	2.40	-	
		I _{OH} = -8mA	4.5V	3.94	-	_	3.80	-	3.70	-	
		I _{OL} = 50μA	2.0V	_	0	0.1	-	0.1	-	0.1	
		I _{OL} = 50μA	3.0V	_	0	0.1	-	0.1	_	0.1	
V_{OL}	Low-Level Output Voltage	I _{OL} = 50μA	4.5V	_	0	0.1	-	0.1	-	0.1	V
	Output Voltage	I _{OL} = 4mA	3.0V	-	-	0.36	-	0.44	-	0.55	
		I _{OL} = 8mA	4.5V	-	-	0.36	-	0.44	-	0.55	
Ι _Ι	Input Current	V _I = GND or 5.5V	5.5V	_	0.01	± 0.1	=	± 1	=	± 2	μA
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}$ $I_O = 0$	5.5V	-	_	4	-	40	-	80	μΑ
Ci	Input Capacitance	$V_i = V_{CC}$ or GND	5.5V	=	3.5	10	=	10	-	10	pF

^{5.} Unused inputs should be held at V_{CC} or Ground.



Switching Characteristics

Symbol /	Pins	Test Conditions	V	Т	A = +25°	С	-40°C to	o +85°C	-40°C to	+125°C	Unit			
Parameter	Pins	rest Conditions	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Unit			
f _{MAX}	SHCP or		3.0V to 3.6V	80	125	_	70	_	65	_				
Maximum Frequency	STCP	Figure1	4.5V to 5.5V	90	70	-	80	-	70	_	MHz			
	SHCP and		3.0V to 3.6V	6.0	_	_	6.5	_	7.0	-				
tw	STCP HIGH or LOW	Figure1	4.5V to 5.5V	5.5	-	-	6.0	-	6.5	-	ns			
Pulse Width	SHR and STR	Figure 1	3.0V to 3.6V	5.0	_	_	5.0	_	5.5	-				
	HIGH or LOW	Figure1	4.5V to 5.5V	5.0	_	_	5.2	_	5.7	-				
	DS to SHCP	Figure1	3.0V to 3.6V	3.5	=	=	3.5	-	3.5	=	ns			
	D3 t0 311CF	rigulei	4.5V to 5.5V	3.0	-	-	3.0	_	3.0	=	115			
t _{SU}	OUD to OTOD	STCP Figure1	3.0V to 3.6V	8.0	_	_	9.0	_	9.5	-				
Set-up Time	SHR to STCP	rigule i	4.5V to 5.5V	5.0	-	_	5.0	_	5.5	-				
	SHCP tp STCP	Figure 1	3.0V to 3.6V	8.0	_	_	8.5	_	9.0	_	ns			
		Figure1	4.5V to 5.5V	5.0	_	_	5.0	_	5.5	_	113			
t _H	DS to SHCP	Figure 1	3.0V to 3.6V	1.5	_	_	1.5	_	1.5	-				
Hold Time	DS 10 SHCP	Figure1	4.5V to 5.5V	2.0	-	_	2.0	_	2.0	-	ns			
	<u> </u>	L CLICE Figure 1	3.0V to 3.6V	4.2	-	_	4.8	_	5.3	-				
trec	SHR to SHCP	SHR to SHCP	SHR to SHCP	SHK to SHCP	SHR to SHCP Figure1	4.5V to 5.5V	2.9	-	_	3.3	_	3.8	-	ns
Recovery Time	OUD (OTOD	Figure 1	3.0V to 3.6V	4.6	_	_	5.3	_	5.8	_				
	SHR to STCP	Figure1	4.5V to 5.5V	3.2	_	_	3.7	_	4.3	_	ns			
		Figure 4.0 45 a F	3.0V to 3.6V	_	5.2	8.5	2.2	9.7	2.2	10.6				
	SHCP toQ7S	Figure1 C _L = 15pF	4.5V to 5.5V	_	3.8	6.3	1.7	7.2	1.7	7.8]			
t _{PLH}	SHCP 10Q/S	Figure 4.0	3.0V to 3.6V	-	7.4	11.5	3.0	13.2	3.0	14.3	ns			
LOW to HIGH		Figure1 C _L = 50pF	4.5V to 5.5V	_	4.8	8.0	2.4	9.1	2.4	10.0	1			
Propagation		Figure 4 C = 45° 5	3.0V to 3.6V	_	5.1	8.3	2.3	9.5	2.3	10.6	T			
Delay	CTCD to Or	Figure1 C _L = 15pF	4.5V to 5.5V	_	3.5	5.7	1.8	6.5	1.8	7.1				
	STCP to Qn	Figure 4 C = F0::F	3.0V to 3.6V	-	7.3	11.9	3.3	13.6	3.3	14.7	ns			
		Figure1 C _L = 50pF	4.5V to 5.5V	_	4.8	7.8	2.6	9.0	2.6	9.8				



Switching Characteristics (cont.)

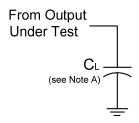
Symbol /	Pins	Test Conditions	V	Т	A = +25°	С	-40°C°C	to +85°C	-40°C°C	to +125°C	Unit		
Parameter	Pilis	rest Conditions	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Unit		
		Figure 4.C = 45pF	3.0V to 3.6V	_	5.5	8.9	2.3	10.2	2.3	11.0			
	CUCD 4-070	Figure 1 C _L = 15pF	4.5V to 5.5V	_	4.1	6.7	1.9	7.6	1.9	8.2			
	SHCP toQ7S	Figure 4.0 50 F	3.0V to 3.6V	_	7.4	12.1	3.0	13.9	3.0	15.1	ns		
		Figure 1 C _L = 50pF	4.5V to 5.5V	_	5.4	8.8	2.5	10.1	2.5	11.0			
		Fig. 22 4 5 4 5 4 5 4 5 4 5 4 5 4 5 4 5 4 5	3.0V to 3.6V	-	5.5	9.1	2.4	10.4	2.4	11.3			
	STCP to Qn	Figure 1 C _L = 15pF	4.5V to 5.5V	-	3.7	6.0	1.9	6.9	1.9	7.5			
tрнLн	STOP to Qn	Figure 4.0 50 F	3.0V to 3.6V	_	7.3	12.0	3.2	13.8	3.2	15.0	ns		
HIGH to LOW		Figure 1 C _L = 50pF	4.5V to 5.5V	_	5.2	8.5	2.6	9.7	2.6	10.5			
Propagation		Figure 4.0 45 F	3.0V to 3.6V	_	5.7	9.5	2.3	10.8	2.3	11.7			
Delay	SHR to	Figure 1 C _L = 15pF	4.5V to 5.5V	=	4.1	6.7	2.0	7.6	2.0	8.2			
	Q7S	Figure 4.0 50 F	3.0V to 3.6V	=	7.5	12.2	3.6	14.0	3.6	15.2	ns		
		Figure 1 C _L = 50pF	4.5V to 5.5V	=	5.4	8.8	2.8	10.1	2.8	11.0			
		Figure 1 C _L = 15pF	3.0V to 3.6V	=	4.1	7.2	2.2	8.2	2.2	8.9	ns		
	STR		4.5V to 5.5V	=	4.1	7.2	2.2	8.2	2.2	8.9			
	to Qn	Figure 4.0 50.5	3.0V to 3.6V	=	5.4	9.4	3.0	10.7	3.0	11.6			
				Figure 1 C _L = 50pF	4.5V to 5.5V	=	5.4	9.4	3.0	10.7	3.0	11.6	
			2.0V	_	39	150	_	185	_	225			
		Figure 1	4.5V	_	14	30	_	37	_	45	ns		
	SHR to Q7S	5	5.0V	_	11	_	_	-	_	_			
t _{PHL}			6.0V	_	12	26	_	31	_	38			
Propagation Delay			2.0V	_	39	125	_	155	_	185			
Delay	 , o	Figure 1	4.5V	-	14	25	_	31	_	37			
	STR to Qn		5.0V	-	11	_	_	-	_	-	ns		
			6.0V	-	12	21	-	26	_	31			
		F. 4	2.0V	_	19	75	_	95	_	110			
outnu	Serial data output Q7S	Figure 1	4.5V	_	7	15	_	19	-	22	ns		
t _{THL}	σαιραί απο		6.0V	_	6	13	-	16	_	19			
Transition Time	Daniel Dat	Fire and	2.0V	_	14	60	_	75	-	90			
11110	Parallel Data Outputs Q _N	Figure 1	4.5V	_	5	12	_	15	-	18	ns		
	Outputs QN		6.0V	_	4	10	_	13	-	15			

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

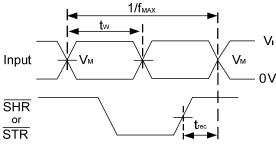
	Parameter	Test	V _{CC} = 5V	Unit
Parameter		Conditions	Тур	Onne
$C_{\sf pd}$	Power dissipation capacitance	f = 1 MHz all outputs switching-no load	51	pF



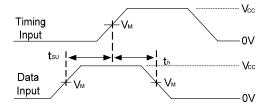
Parameter Measurement Information



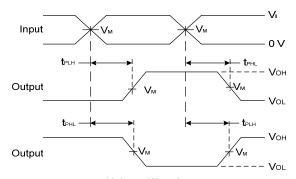
.,	Inj	outs	
Vcc	VI	t _r /t _f	V _M
4.5V	Vcc	6ns	V _{CC} /2
5.0V	V _{CC}	6ns	V _{CC} /2



Voltage Waveform Pulse Duration and Recovery Time



Voltage Waveform Set-up and Hold Times



Voltage Waveform Propagation Delay Times **Inverting and Non Inverting Outputs**

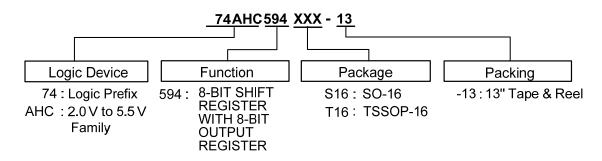
Notes:

- A. Includes test lead and test apparatus capacitance.B. All pulses are supplied at pulse repetition rate ≤ 10MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{PD} .

Figure 1 Load Circuit and Voltage Waveforms



Ordering Information

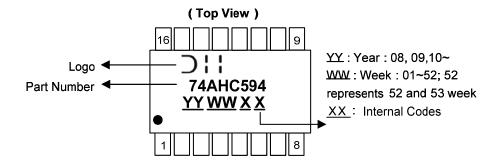


Part Number	Package Code	Dookoging	7" Tape and	Reel (Note 6)
Part Number	Package Code	Packaging	Quantity	Part Number Suffix
74AHC594S16-13	S16	SO-16	2500/Tape & Reel	-13
74AHC594T16-13	T16	TSSOP-16	2500/Tape & Reel	-13

Note: 6. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf

Marking Information

(1) SO-16, TSSOP16



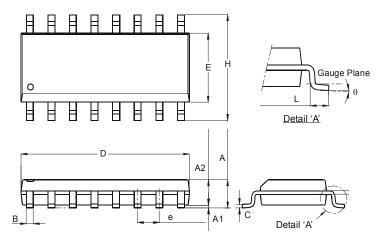
Part Number	Package
74AHC594S16	SO-16
74AHC594T16	TSSOP-16



Package Outline Dimensions (All dimensions in mm.)

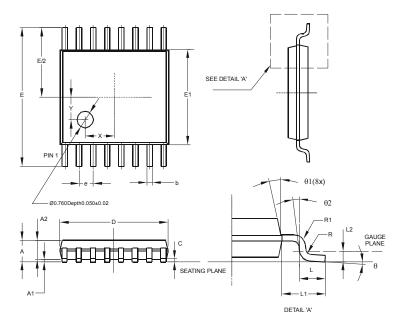
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-16



	SO-16				
Dim	Min	Max			
Α	1.40	1.75			
A1	0.10	0.25			
A2	1.30	1.50			
В	0.33	0.51			
O	0.19	0.25			
D	9.80	10.00			
Е	3.80	4.00			
е	1.27	Тур			
H	5.80	6.20			
L	0.38	1.27			
Θ 0° 8°					
All D	imension	s in mm			

Package Type: TSSOP-16



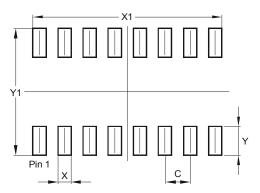
TSSOP-16				
Dim	Min	Max	Тур	
Α	-	1.08	-	
A1	0.05	0.15	-	
A2	0.80	0.93	-	
b	0.19	0.30	-	
С	0.09	0.20	1	
D	4.90	5.10	1	
Е	6.40 BSC			
E1	4.30	4.50	-	
е	0.65 BSC			
L	0.45	0.75	-	
L1	1.00 REF			
L2	0.25 BSC			
R	0.09	-	-	
R1	0.09	ı	ı	
X	ı	ı	1.350	
Υ	ı	ı	1.050	
Θ	0°	8°	-	
Θ1	5°	15°	-	
Θ2	0°	-	-	
All Dimensions in mm				



Suggested Pad Layout

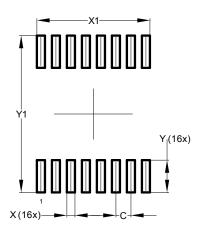
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-16



Dimensions	Value (in mm)	
С	1.270	
Х	0.670	
X1	9.560	
Y	1.450	
Y1	6.400	

Package Type: TSSOP-16



Dimensions	Value (in mm)	
С	0.650	
Х	0.350	
X1	4.900	
Y	1.400	
Y1	6.800	

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